

INFORMATION DISCLOSURE STATEMENT BY APPLICANT

Sheet 1 | of | 1

NON PATENT LITERATURE DOCUMENTS				
Examiner Initials*	Cite No.'	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the Item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T'	
DCD		LAMMERS, DAVID, "Euro, Japan go to extremes for EUV," EE Times, 10/18/2002, 6 pages		
DCD		ITO, H., "Chemical amplfication resists: History and development within IBM," http://researchweb.watson.ibm.com/journal/rd/411/ito.txt, 1997 IBM, 12 pages		
DCD		"Introduction to Electron Beam Lithography," http://dot.che.gatech.edu/henderson/introduction_to_electron_beam_lithography.htm, 13		
DCD		Definition of 'PHOTORESIST" from Wikipedia, 2003, one page		
DCD		MEDEIROS, D.R., ET AL., "Recent progress in electron-beam resists for advanced mask-making," IBM J. RES. & DEV. vol 45, no. 5, 09/2001, pps. 639-650	_	
DCD		COBB, JONATHAN, ET AL., "Controlling line-edge roughness to within reasonable limits," Proceedings of SPIE Vol. 5039 (2003), pps. 376-383		
DCD		LINTON, T., ET AL., "Determination of the Line Edge Roughness Specification for 34 nm Devices," TCAD Division, Intel Corporation, 2002 IEEE, pps. 303-306		
DCD		STEWART, MICHAEL D., ET AL., "Diffusion Induced Line Edge Roughness," Advances in Resist Technology and Processing XX, Proceedings of SPIE Vol. 5039, 2003, pps.		
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Examiner /Daborah Chacko-Davis/	Date 09/21/2006
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<sup>\*</sup>Examiner: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Oraw line through citation if not in conformance and not considered. Include copy of this form with next communication.

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